NSN 5962-01-033-5509

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View Online at https://aerobasegroup.com/nsn/5962-01-033-5509
Body Length:
Between 0.747 inches and 0.815 inches
Body Width:
Between 0.220 inches and 0.280 inches
Body Height:
0.200 inches
Maximum Power Dissipation Rating:
525.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+200.0 degrees celsius
End Application:
Building block 57 fscm 30003
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/enable and programmable and programmed and high speed and wire-or
outputs
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Gold
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
60.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Rom
Precious Material And Location:
Terminals gold
Test Data Document:
06424-10560 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:

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N/a

16 printed circuit

Shelf Life:

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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